Excellent Integrated System Limited

Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

<u>Diodes Incorporated</u> <u>DMP2066LDM-7</u>

For any questions, you can email us directly: sales@integrated-circuit.com

Distributor of Diodes Incorporated: Excellent Integrated System Limited

Datasheet of DMP2066LDM-7 - MOSFET P-CH 20V 4.6A SOT-26

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com





DMP2066LDM

P-CHANNEL ENHANCEMENT MODE MOSFET

Features

- Low R_{DS(ON)}:
 - $40 \text{ m}\Omega$ @V_{GS} = -4.5V
 - $70 \text{ m}\Omega$ @V_{GS} = -2.5V
- Low Input/Output Leakage
- Lead Free By Design/RoHS Compliant (Note 1)
- "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

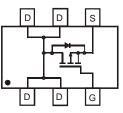
Mechanical Data

- Case: SOT26
- Case Material Molded Plastic. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Weight: 0.008 grams (approximate)

SOT26



Top View



Top View Internal Schematic

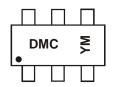
Ordering Information (Note 3)

Part Number	Case	Packaging
DMP2066LDM-7	SOT26	3000/Tape & Reel
DMP2066LDMQ-7	SOT26	3000/Tape & Reel

Notes:

- 1. No purposefully added lead.
- 2. Diodes Inc's "Green" policy can be found on our website at http://www.diodes.com. 3. For packaging details, go to our website at http://www.diodes.com.

Marking Information



DMC = Product Type Marking Code

YM = Date Code Marking

Y = Year (ex: V = 2008)

M = Month (ex: 9 = September)

Date Code Key

Year	2008		2009	2010		2011	2012		2013	2014		2015
Code	V		W	Х		Υ	Z		Α	В		С
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

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DMP2066LDM

Maximum Ratings @TA = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		V_{DSS}	-20	V
Gate-Source Voltage		V_{GSS}	±12	V
Drain Current (Note 4) Continuous	$T_A = 25$ °C $T_A = 70$ °C	ID	-4.6 -3.7	А
Pulsed Drain Current (Note 5)		I _{DM}	-18	Α
Body-Diode Continuous Current (Note 4)		Is	2.0	Α

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 4)	P_{D}	1.25	W
Thermal Resistance, Junction to Ambient (Note 4); Steady-State	$R_{ hetaJA}$	100	°C/W
Operating and Storage Temperature Range	TJ, T _{STG}	-55 to +150	°C

Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
STATIC PARAMETERS							
Drain-Source Breakdown Voltage	BV _{DSS}	-20	_	_	V	$I_D = -250 \mu A$, $V_{GS} = 0 V$	
Zero Gate Voltage Drain Current $T_J = 25^{\circ}C$	I _{DSS}	_	_	-1	μΑ	$V_{DS} = -20V, V_{GS} = 0V$	
Gate-Body Leakage Current	I _{GSS}	_	_	±100	nA	$V_{DS} = 0V, V_{GS} = \pm 12V$	
Gate Threshold Voltage	V _{GS(th)}	-0.6	-0.96	-1.2	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
On State Drain Current (Note 6)	I _{D (ON)}	-15	_	_	Α	$V_{GS} = -4.5V, V_{DS} = -5V$	
Static Drain-Source On-Resistance (Note 6)	R _{DS} (ON)	_	29 55	40 70	mΩ	$V_{GS} = -4.5V$, $I_D = -4.6A$ $V_{GS} = -2.5V$, $I_D = -3.8A$	
Forward Transconductance (Note 6)	g _{FS}	_	9	_	S	$V_{DS} = -10V, I_{D} = -4.6A$	
Diode Forward Voltage (Note 6)	V_{SD}	-0.5	-0.72	-1.4	V	I _S = -2.1A, V _{GS} = 0V	
Maximum Body-Diode Continuous Current (Note 4)	Is	_	_	1.7	Α	_	
DYNAMIC PARAMETERS (Note 7)						•	
Input Capacitance	C _{iss}	_	820	_	pF	V _{DS} = -15V, V _{GS} = 0V f = 1.0MHz	
Output Capacitance	Coss	_	200	_	pF		
Reverse Transfer Capacitance	Crss	_	160	_	pF	1 = 1.01/11/12	
Gate Resistance	R_{G}	_	2.5	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$ f = 1.0MHz	
SWITCHING CHARACTERISTICS							
Total Gate Charge	Q_G	_	10.1	_		101/1/ 451/	
Gate-Source Charge	Q_{GS}	_	1.5	_	nC	$V_{DS} = -10V, V_{GS} = -4.5V,$ $I_{D} = -4.5A$	
Gate-Drain Charge	Q_{GD}	_	4.3	_		ID4.3A	
Turn-On Delay Time	t _{d(on)}		4.4	_		$V_{DS} = -10V, V_{GS} = -4.5V,$ $I_{D} = -1A, R_{G} = 6.0\Omega$	
Rise Time	t _r	_	9.9	_			
Turn-Off Delay Time	t _{d(off)}	_	28.0	_	ns		
Fall Time	t _f		23.4	_			

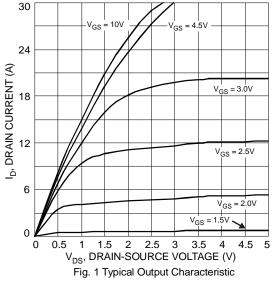
Notes:

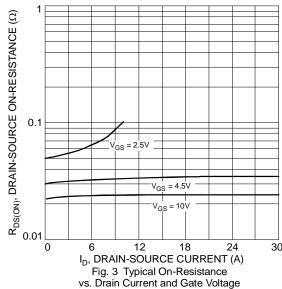
- 4. Device mounted on 1"x1", FR-4 PC board with 2 oz. Copper and test pulse width t \leq 10s. 5. Repetitive Rating, pulse width limited by junction temperature. 6. Test pulse width t = 300 μs .

- 7. Guaranteed by design. Not subject to production testing.

DIODES

DMP2066LDM





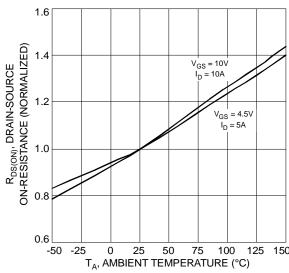
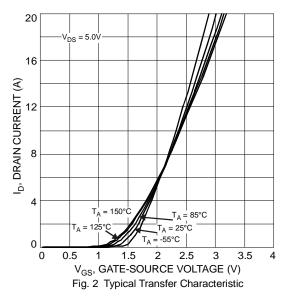
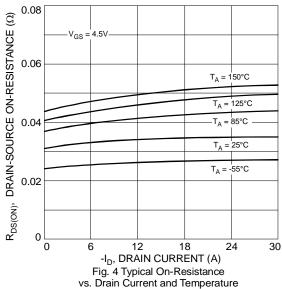


Fig. 5 Normalized On-Resistance vs. Ambient Temperature





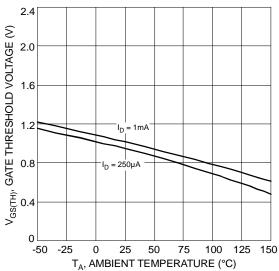
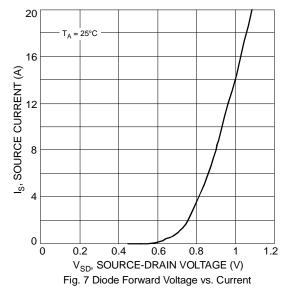
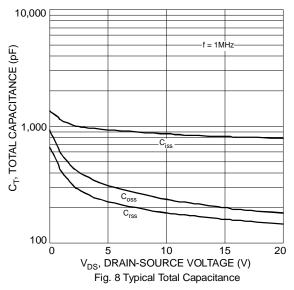


Fig. 6 Gate Threshold Variation vs. Ambient Temperature



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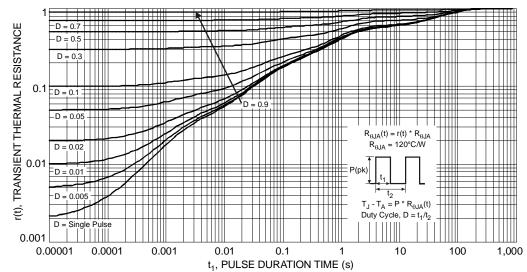
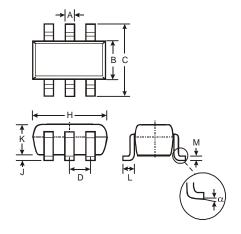


Fig. 9 Transient Thermal Response

Package Outline Dimensions



SOT26							
Dim	Min	Max	Тур				
Α	0.35	0.50	0.38				
В	1.50	1.70	1.60				
C	2.70	3.00	2.80				
D	_	_	0.95				
Н	2.90	3.10	3.00				
7	0.013	0.10	0.05				
K	1.00	1.30	1.10				
١	0.35	0.55	0.40				
M	0.10	0.20	0.15				
α	0°	8°	_				
All Dimensions in mm							

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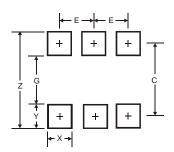
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DMP2066LDM

Suggested Pad Layout



Dimensions	Value (in mm)
Z	3.20
G	1.60
Х	0.55
Υ	0.80
С	2.40
E	0.95

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